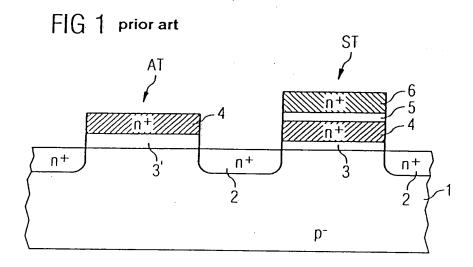
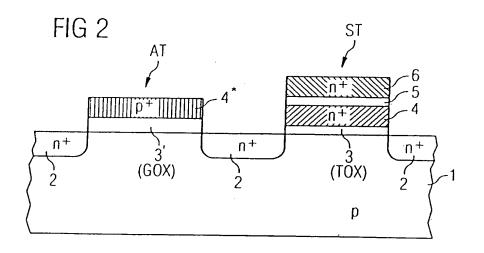
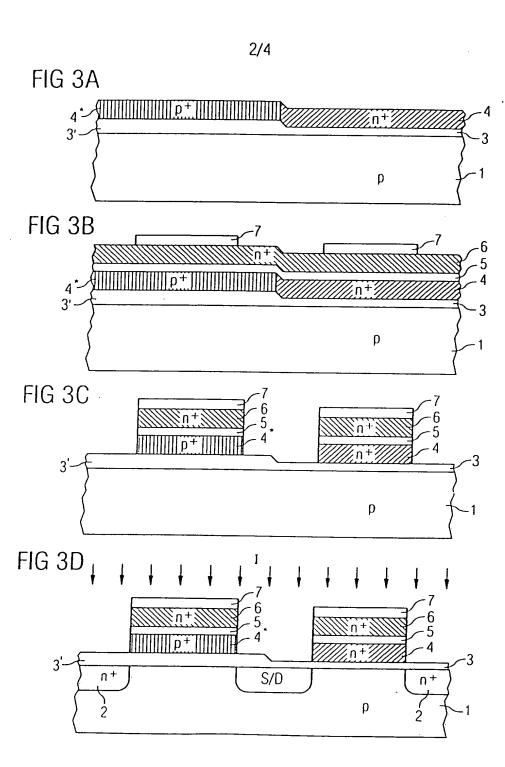
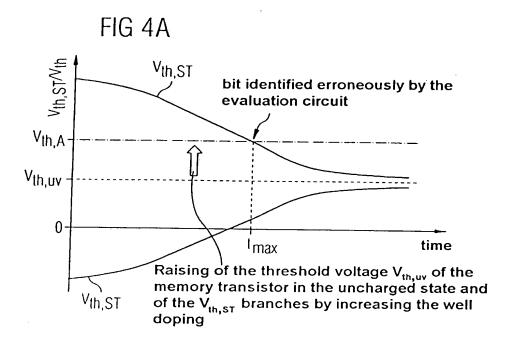
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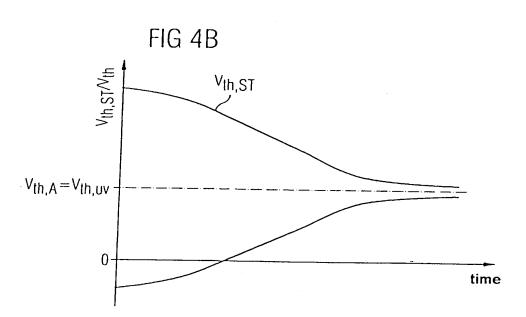






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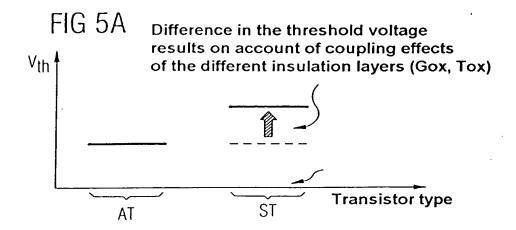


FIG 5B

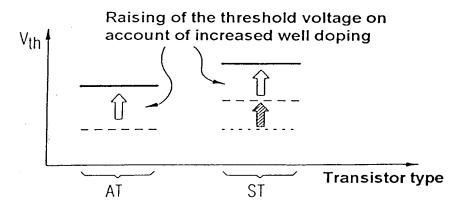


FIG 5C

Change in the work function of the control layer in the selection transistor (e.g. by means of p-type doping)

AT

Transistor type